			H·A
	Application No.	Applicant(s)	
Madica of Allower Wes	10/716,994	MEARS ET AL.	
Notice of Allowability	Examiner	Art Unit	
	Thinh T Nguyen	2818	
The MAILING DATE of this communication app All claims being allowable, PROSECUTION ON THE MERITS IS herewith (or previously mailed), a Notice of Allowance (PTOL-85; NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT R of the Office or upon petition by the applicant. See 37 CFR 1.313	(OR REMAINS) CLOSED in the or other appropriate communic CIGHTS. This application is sub	is application. If not includ cation will be mailed in due	ed course. <b>THIS</b>
1. X This communication is responsive to 11/19/2003.			
2. 🔀 The allowed claim(s) is/are <u>72-97</u> .	•		
3. $igotimes$ The drawings filed on <u>19 November 2003</u> are accepted by	the Examiner.		
4. ☐ Acknowledgment is made of a claim for foreign priority unallocation a) ☐ All b) ☐ Some* c) ☐ None of the:  1. ☐ Certified copies of the priority documents have 2. ☐ Certified copies of the priority documents have 3. ☐ Copies of the certified copies of the priority documents have International Bureau (PCT Rule 17.2(a)).  * Certified copies not received:	e been received. e been received in Application N	No	ition from the
Applicant has THREE MONTHS FROM THE "MAILING DATE" noted below. Failure to timely comply will result in ABANDONN THIS THREE-MONTH PERIOD IS NOT EXTENDABLE.		reply complying with the re	quirements
<ol> <li>A SUBSTITUTE OATH OR DECLARATION must be subm INFORMAL PATENT APPLICATION (PTO-152) which giv</li> </ol>	nitted. Note the attached EXAM res reason(s) why the oath or de	INER'S AMENDMENT or Neclaration is deficient.	IOTICE OF
<ol> <li>CORRECTED DRAWINGS ( as "replacement sheets") must (a) including changes required by the Notice of Draftspers 1) hereto or 2) to Paper No./Mail Date (b) including changes required by the attached Examiner' Paper No./Mail Date (like including changes required by the attached Examiner' Paper No./Mail Date (like including indicia such as the application number (see 37 CFR 1) each sheet. Replacement sheet(s) should be labeled as such in the control of the co</li></ol>	son's Patent Drawing Review ( - 's Amendment / Comment or in  1.84(c)) should be written on the c the header according to 37 CFR 1	the Office action of drawings in the front (not the l.121(d).	
attached Examiner's comment regarding REQUIREMENT			
Attachment(s)			
1. Notice of References Cited (PTO-892)	<del></del>	mal Patent Application (PT	O-152)
2. Notice of Draftperson's Patent Drawing Review (PTO-948)		mary (PTO-413), iil Date	
<ol> <li>Information Disclosure Statements (PTO-1449 or PTO/SB/0 Paper No./Mail Date</li> </ol>	08), 7. 🛭 Examiner's An	nendment/Comment	
4. Examiner's Comment Regarding Requirement for Deposit	8. 🛭 Examiner's Sta	atement of Reasons for Allo	owance
of Biological Material	9. 10ther		
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	David Nelms Supervisory Patent Examines		
	Supervisory Patent Examiner Technology Center 2800		
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**DETAILED ACTION** 

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Examiner's comment.

1. The examiner can not identifies patent AD assigned to Yamazaki on the IDS sent

to the Office by the Applicants on November 19<sup>th</sup> 2003. for this reference to be

considered by the Office, the Applicants need to sent in the correct identification of this

reference before paying the issue fee.

Reason for allowance

2. Claims 72-97 are allowed. The following is an examiner's statement of reason for

allowance:

I/ group I : claims 72-87:

None of the references of record teaches or suggests the claimed

SEMICONDUCTOR DEVICE INCLUDING BAND-ENGINEERED

**SUPERLATTICE** having the limitations

-- " groups of layers arranged an alternating pattern of first and second groups of

layers, with each first group of layers comprising three base semiconductor

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monolayers, and each second group of layers comprising five base semiconductor monolayers; said energy-band modifying layer comprising at least one non-semiconductor monolayer constrained within a crystal lattice of adjacent base semiconductor portions. "--

and all other limitations as recited in claim 72.

II/ group II: claims 88-97:

None of the references of record teaches or suggests the claimed

## SEMICONDUCTOR DEVICE INCLUDING BAND-ENGINEERED

**SUPERLATTICE** having the limitations

-- " groups of layers arranged an alternating pattern of first and second groups of layers, with each first group of layers comprising three base semiconductor monolayers, and each second group of layers comprising five base semiconductor monolayers; said energy-band modifying layer comprising at least one oxygen monolayer constrained within a crystal lattice of adjacent base semiconductor portions. "--

and all other limitations as recited in claim 88.

Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance".

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Conclusion

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3. The prior art made of record and not relied upon is considered pertinent to

applicant's disclosure: Seabaugh (US patent 5,796,119) disclose a silicon resonant

tunneling.

4. Any inquiry concerning this communication or earlier communications from the

examiner should be directed to Thinh T Nguyen whose telephone number is 571-272-

1790. The examiner can normally be reached on Monday-Friday 9:00am-6:00pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's

supervisor, David Nelms can be reached at 571-272-1787. The fax phone numbers for

the organization where this application or proceeding is assigned are (703) 872-9306 for

regular communications and (703) 872-9319 for After Final communications.

Any inquiry of a general nature or relating to the status of this application or

proceeding should be directed to the receptionist whose telephone number is (703) 308-

0956.

Supervisory Patent Examiner
Technology Center 2800

Thinh T Nguyen

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